

- Current transfer ratio (CTR: 20~300% at $I_F = \pm 10\text{mA}$, $V_{CE} = 5\text{V}$)
- High isolation voltage between input and output (Viso =5000Vrms)
- Collector - emitter breakdown voltage $V_{CE0} \geq 80\text{V}$
- Operating Temperature: -55 ~110
- Environmentally friendly products, compliant with CQC, UL, and VDE requirements

- Case: DIP4 DIP4 - M SMD4
- Molding Compound: UL Flammability Classification Rating 94V-0
- Terminals:



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Input	Forward Current	IF	±60	mA
	Power Dissipation	PD	100	mW
	Power Dissipation Derating factor (above Ta = 100°C)	PDD	2.9	mW/°C
	Thermal Resistance Junction-Ambient	RthJ-A	325	°C/W
	Thermal Resistance Junction-Case	RthJ-C	200	°C/W
Output	Power Dissipation	PC	150	mW
	Collector Current	IC	50	mA
	Collector-Emitter Voltage	VCEO	80	V
	Emitter-Collector Voltage	VECO	7	V

Total Power Dissipation		PTOT	200	mW
Isolation Voltage *1		VISO	5000	Vrms
Operating Temperature		TOPR	-55 ~ +100	°C
Storage Temperature Range		TSTG	-55 ~ +125	°C
Soldering Temperature *2		TSOL	260	°C

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Input	Forward Voltage	VF	IF=±20mA	-	1.2	1.4	V
	Terminal Capacitance	Ct	V=0,f=1kHz	-	30	250	pF
	Collector-Emitter Dark						
	Current	ICEO	VCE = 20V, IF = 0	-	-	100	nA
Output	Collector-Emitter						
	Breakdown Voltage						





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